

Silicon Carbide Diode 4 January 2017

Product data sheet

1. General description

Silicon Carbide Schottky diode in a TO263 (D2PAK) plastic package, designed for high frequency switched-mode power supplies.

2. Features and benefits

- Highly stable switching performance
- High forward surge capability I_{FSM}
- Extremely fast reverse recovery time
- Superior in efficiency to Silicon Diode alternatives
- Reduced losses in associated MOSFET
- Reduced EMI
- Reduced cooling requirements
- RoHS compliant

3. Applications

- Power factor correction
- Telecom/Server SMPS
- UPS
- PV inverter
- PC Silverbox
- LED/OLED TV
- Motor Drives

4. Quick reference data

Table 1. Qui	ck reference data					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{RRM}	repetitive peak reverse voltage		-	-	650	V
I _{F(AV)}	average forward current	$\begin{array}{l} \delta = 0.5 \hspace{0.2cm} ; \hspace{0.2cm} T_{mb} \leq \hspace{0.2cm} 136 \hspace{0.2cm} ^{\circ} C; \hspace{0.2cm} square-wave \\ \text{pulse}; \hspace{0.2cm} \underline{\text{Fig. 1}}; \hspace{0.2cm} \underline{\text{Fig. 2}}; \hspace{0.2cm} \underline{\text{Fig. 3}}; \hspace{0.2cm} \underline{\text{Fig. 4}} \end{array}$	-	-	4	A
Tj	junction temperature		-	-	175	°C
Static chara	acteristics	· · · · ·	· ·			
V _F	forward voltage	I _F = 4 A; T _j = 25 °C; <u>Fig. 6</u>	-	1.5	1.7	V
		I _F = 4 A; T _j = 150 °C; <u>Fig. 6</u>	-	1.8	2.1	V
Dynamic ch	naracteristics	· · · · · ·				
Qr	recovered charge	$I_F = 4 \text{ A; } dI_F/dt = 500 \text{ A}/\mu\text{s; } V_R = 400 \text{ V;} T_j = 25 °C; Fig. 7$	-	7	-	nC

5. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	n.c.	not connected		K A
2	К	cathode[1]		001aaa020
3	А	anode		
mb	К	mounting base; connected to cathode		

[1] It is not possible to connect to pin 2 of the TO263 package.

6. Ordering information

Table 3. Ordering information						
Type number	Package					
	Name	Description	Version			
NXPSC04650B	-	plastic single-ended surface-mounted package (D2PAK); 3 leads (one lead cropped)	TO263N			

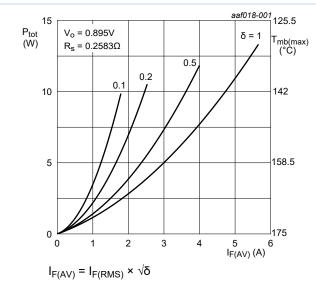
Silicon Carbide Diode

7. Limiting values

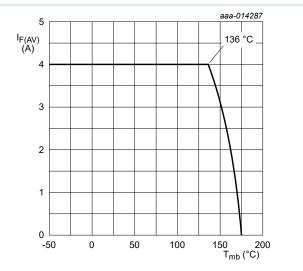
Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{RRM}	repetitive peak reverse voltage		-	650	V
V _{RWM}	crest working reverse voltage		-	650	V
V _R	reverse voltage	DC	-	650	V
I _{F(AV)}	average forward current	δ = 0.5 ; T _{mb} ≤ 136 °C; square-wave pulse; <u>Fig. 1; Fig. 2</u> ; <u>Fig. 3</u> ; <u>Fig. 4</u>	-	4	A
I _{FRM}	repetitive peak forward current	δ = 0.5 $$; t_p = 25 $\mu s;$ square-wave pulse	-	8	A
I _{FSM}	non-repetitive peak	t_p = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse	-	24	А
	forward current	t_p = 10 µs; $T_{j(init)}$ = 25 °C; square-wave pulse	-	235	A
T _{stg}	storage temperature		-55	175	°C
Tj	junction temperature		-	175	°C





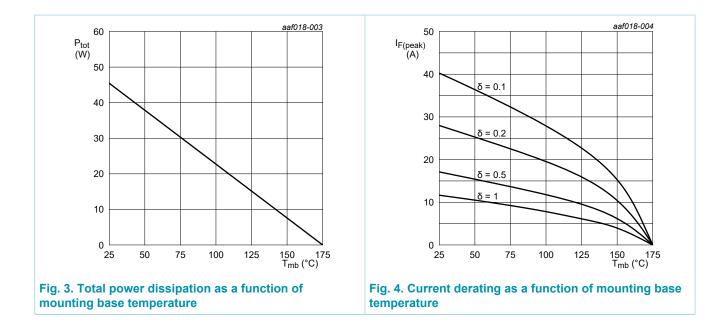




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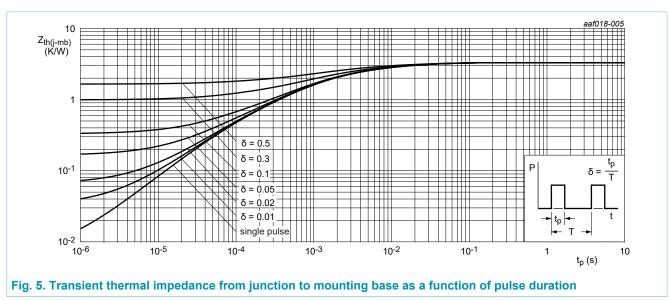
Silicon Carbide Diode



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8. Thermal characteristics

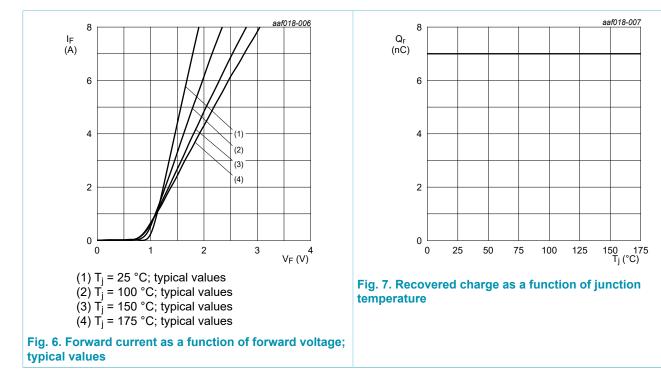
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-mb)}	thermal resistance from junction to mounting base	<u>Fig. 5</u>	-	-	3.3	K/W
R _{th(j-a)}	thermal resistance from junction to ambient free air	Device mounted on an FR4 Printed- Circuit Board (PCB)	-	50	-	K/W



Silicon Carbide Diode

9. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics					
V _F	forward voltage	I _F = 4 A; T _j = 25 °C; <u>Fig. 6</u>	-	1.5	1.7	V
		I _F = 4 A; T _j = 150 °C; <u>Fig. 6</u>	-	1.8	2.1	V
I _R	reverse current	V _R = 650 V; T _j = 25 °C	-	-	170	μA
		V _R = 650 V; T _j = 150 °C	-	-	550	μA
Dynamic ch	naracteristics	· · · · · · · · · · · · · · · · · · ·				
Q _r	recovered charge	I _F = 4 A; dI _F /dt = 500 A/µs; V _R = 400 V; T _j = 25 °C; <u>Fig. 7</u>	-	7	-	nC
C _d	diode capacitance	f = 1 MHz; V _R = 1 V; T _j = 25 °C	-	130	-	pF
		f = 1 MHz; V _R = 300 V; T _j = 25 °C	-	16	-	pF
		f = 1 MHz; V _R = 600 V; T _i = 25 °C	-	13	-	pF



Silicon Carbide Diode

10. Package outline

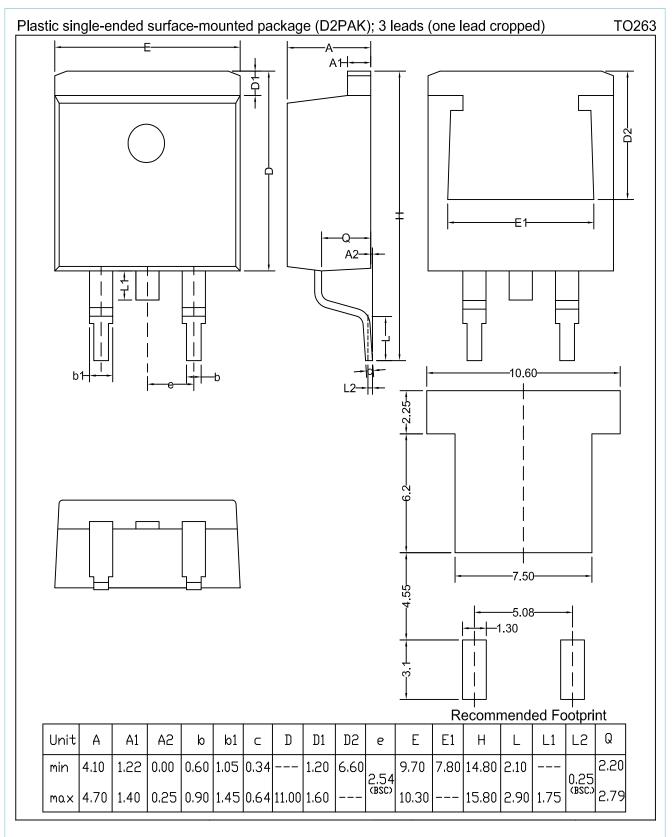


Fig. 8. Package outline TO263N

NXPSC04650B

Product data sheet

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11. Legal information

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Document status [1][2]	Product status [<u>3]</u>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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Silicon Carbide Diode

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12. Contents

1.	General description	1
2.	Features and benefits	1
3.	Applications	1
4.	Quick reference data	1
5.	Pinning information	2
6.	Ordering information	2
7.	Limiting values	3
8.	Thermal characteristics	5
9.	Characteristics	6
10	. Package outline	7
11.	Legal information	8

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